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Vishay Siliconix

Automotive P-Channel 150 V (D-S) 175 °C MOSFET

PowerPAK® 1212-8W Single D D D B T Top View Bottom View

Marking Code: Q026

PRODUCT SUMMARY	
V _{DS} (V)	-150
$R_{DS(on)}$ (Ω) at $V_{GS} = -10 \text{ V}$	1.095
I _D (A)	-16
Configuration	Single
Package	PowerPAK 1212-8W

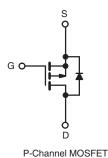
FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified ^d
- 100 % Rq and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





ROHS COMPLIANT HALOGEN FREE



ABSOLUTE MAXIMUM RATINGS	T _C = 25 °C, unles	s otherwise noted)		
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-source voltage		V _{DS}	-150	V	
Gate-source voltage		V_{GS}	± 20	V	
Continuous drain current ^a	T _C = 25 °C	1	-4.7		
Continuous drain current "	T _C = 125 °C	I _D	-2.75		
Continuous source current (diode conduction) ^a		I _S	-8	Α	
Pulsed drain current b		I _{DM}	-19		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	-4		
Single pulse avalanche energy	L=0.1 mn	E _{AS}	0.8	mJ	
Maximum power dissipation ^b	T _C = 25 °C	Ъ	62.5	W	
Maximum power dissipation ~	T _C = 125 °C	P_{D}	20	VV	
perating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	
Soldering recommendations (peak temperature)	e, f		260	C	

THERMAL RESISTANCE RATINGS			
PARAMETER	SYMBOL	LIMIT	UNIT
Junction-to-ambient PCI	B mount ^c R _{thJA}	81	°C/W
Junction-to-case (drain)	R _{thJC}	2.4	G/VV

Notes

- a. Package limited
- b. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- c. When mounted on 1" square PCB (FR4 material)
- d. Parametric verification ongoing
- e. See solder profile (www.vishay.com/doc?73257). The PowerPAK 1212-8W is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- f. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static								
Drain-source breakdown voltage	V _{DS}	V_{GS}	= 0, I _D = -250 μA	-150	-	-	.,	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	· V _{GS} , I _D = -250 μA	-2.5	-3	-3.5	V	
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, V _{GS} = ± 20 V	-	-	± 100	nA	
Zero gate voltage drain current		$V_{GS} = 0 V$	V _{DS} = -150 V	-	-	-1		
	I _{DSS}	V _{GS} = 0 V	V _{DS} = -150 V, T _J = 125 °C	-	-	-50	μΑ	
		V _{GS} = 0 V	V _{DS} = -150 V, T _J = 175 °C	-	-	-150		
On-state drain current ^a	I _{D(on)}	V _{GS} = -10 V	$V_{DS} \ge 5 V$	-5	-	-	Α	
	R _{DS(on)}	V _{GS} = -10 V	I _D = -2.4 A	-	0.910	1.095	- V nA μA	
Drain-source on-state resistance a		V _{GS} = -10 V	I _D = -2.4 A, T _J = 125 °C	-	-	2.290		
		V _{GS} = -10 V	I _D = -2.4 A, T _J = 175 °C	-	-	2.570		
Forward transconductance b	9 _{fs}	V _{DS}	= -15 V, I _D = -1 A	-	2.5	-	S	
Dynamic ^b								
Input capacitance	C _{iss}	V _{GS} = 0 V	V _{DS} = -75 V, f = 1 MHz	-	305	385		
Output capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = -75 V, f = 1 MHz	-	18	24	pF	
Reverse transfer capacitance	C _{rss}	$V_{GS} = 0 V$	$V_{DS} = -75 \text{ V}, f = 1 \text{ MHz}$	-	10	13		
Total gate charge ^c	Qg	V _{GS} = -10 V	$V_{DS} = -75 \text{ V}, I_{D} = -1 \text{ A}$	-	8	11		
Gate-source charge c	Q_{gs}	V _{GS} = -10 V	$V_{DS} = -75 \text{ V}, I_{D} = -1 \text{ A}$	-	1.7	-	nC	
Gate-drain charge ^c	Q_{gd}	V _{GS} = -10 V	$V_{DS} = -75 \text{ V}, I_{D} = -1 \text{ A}$	-	2.5	-		
Gate resistance	R_g		f = 1 MHz	2.8	4.7	7.6	Ω	
Turn-on delay time ^c	t _{d(on)}			-	7.1	10		
Rise time ^c	t _r	V _{DD} =	= -75 V, R _L = 75 Ω	-	2.3	3.3		
Turn-off delay time ^c	t _{d(off)}	I _D ≅ -1 A, '	$V_{GEN} = -10 \text{ V}, R_g = 1 \Omega$	-	15.3	21.5	118	
Fall time ^c	t _f			-	2.6	3.8		
Source-Drain Diode Ratings and Chara	cteristic ^b							
Pulsed current ^a	I _{SM}			-	-	-20	Α	
	Olvi						1	

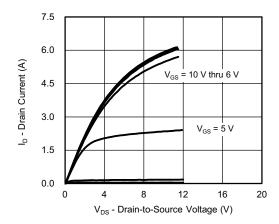
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

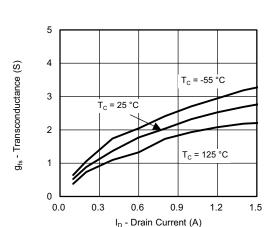
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



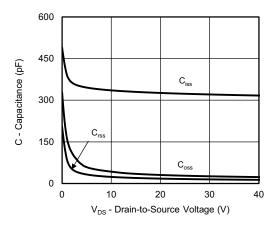
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



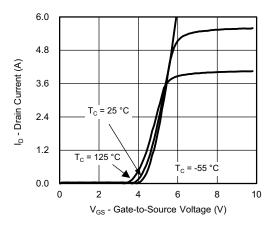
Output Characteristics



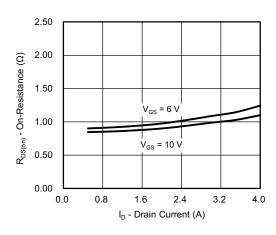
Transconductance



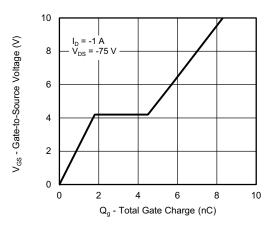
Capacitance



Transfer Characteristics



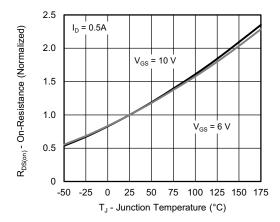
On-Resistance vs. Drain Current



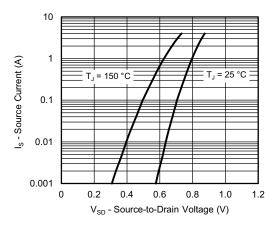
Gate Charge



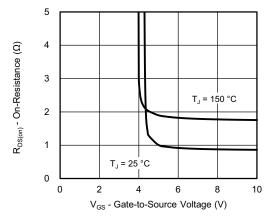
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



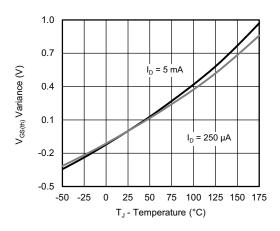
On-Resistance vs. Junction Temperature



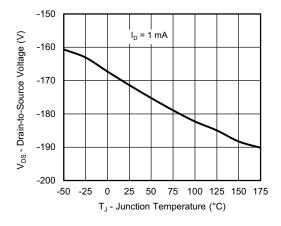
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage

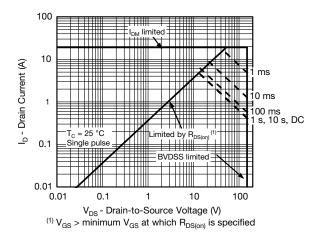


Drain Source Breakdown vs. Junction Temperature

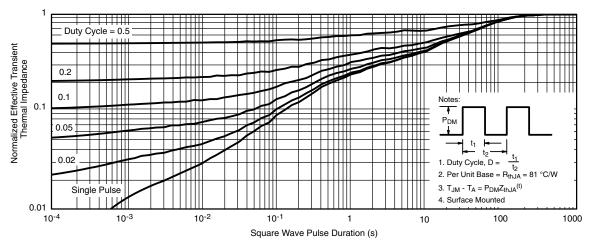
For technical questions, contact: automostech



THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



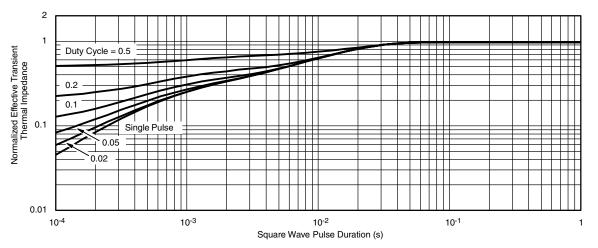
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

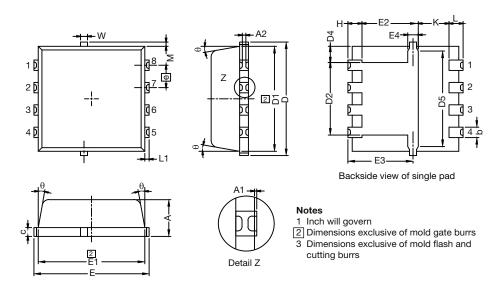
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg276468.



PowerPAK® 1212-8W Case Outline



DIM.	MILLIMETERS			INCHES				
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		
Α	0.97	1.04	1.12	0.038	0.041	0.044		
A1	0	-	0.05	0	-	0.002		
A2	0	-	0.13	0	-	0.005		
b	0.23	0.30	0.41	0.009	0.012	0.016		
С	0.23	0.28	0.33	0.009	0.011	0.013		
D	3.20	3.30	3.40	0.126	0.130	0.134		
D1	2.95	3.05	3.15	0.116	0.120	0.124		
D2	1.98	2.11	2.24	0.078	0.083	0.088		
D4	0.47 typ.				0.0185 typ.			
D5	2.3 typ.			0.090 typ.				
Е	3.20	3.30	3.40	0.126	0.130	0.134		
E1	2.95	3.05	3.15	0.116	0.120	0.124		
E2	1.47	1.60	1.73	0.058	0.063	0.068		
E3	1.75	1.85	1.98	0.069	0.073	0.078		
E4		0.34 typ.			0.34 typ. 0.013 typ.			
е		0.65 BSC.		0.026 BSC				
K		0.86 typ.		0.034 typ.				
Н	0.30	0.41	0.51	0.012	0.016	0.020		
L	0.30	0.43	0.56	0.012	0.017	0.022		
L1	0.06	0.13	0.20	0.002	0.005	0.008		
θ	0°	-	12°	0°	-	12°		
W	0.15	0.25	0.36	0.006	0.010	0.014		
М		0.125 typ.			0.005 typ.			

DWG: 6032



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